

MOSFETs Silicon N-Channel MOS (U-MOSVII)

TPC8088

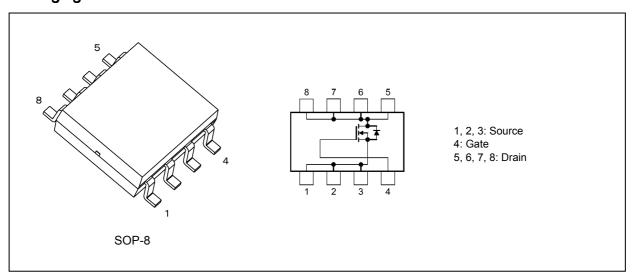
1. Applications

- · Notebook PCs
- · Mobile Handsets

2. Features

- (1) Small footprint due to a small and thin package
- (2) Low drain-source on-resistance: $R_{DS(ON)} = 1.9 \text{ m}\Omega$ (typ.) ($V_{GS} = 10 \text{ V}$)
- (3) Low leakage current: $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 30 \text{ V)}$
- (4) Enhancement mode: V_{th} = 1.3 to 2.3 V (V_{DS} = 10 V, I_{D} = 1.0 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) (T_a = 25°C unless otherwise specified)

| Characteristics | | | | Rating | Unit |
|-------------------------------|------------|----------|------------------|------------|------|
| Drain-source voltage | | | V _{DSS} | 30 | V |
| Gate-source voltage | | | V _{GSS} | ±20 | |
| Drain current (DC) | | (Note 1) | I _D | 18 | А |
| Drain current (pulsed) | | (Note 1) | I _{DP} | 72 | |
| Power dissipation | (t = 10 s) | (Note 2) | P _D | 1.9 | W |
| Power dissipation | (t = 10 s) | (Note 3) | P _D | 1.0 | W |
| Single-pulse avalanche energy | | (Note 4) | E _{AS} | 842 | mJ |
| Avalanche current | | | I _{AR} | 18 | Α |
| Channel temperature | | | T _{ch} | 150 | °C |
| Storage temperature | | | T _{stg} | -55 to 150 | 7 |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



5. Thermal Characteristics

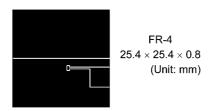
| Characteristics | | | Symbol | Max | Unit |
|---------------------------------------|------------|----------|-----------------------|------|------|
| Channel-to-ambient thermal resistance | (t = 10 s) | (Note 2) | R _{th(ch-a)} | 65.7 | °C/W |
| Channel-to-ambient thermal resistance | (t = 10 s) | (Note 3) | R _{th(ch-a)} | 125 | °C/W |

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4: V_{DD} = 24 V, T_{ch} = 25°C (initial), L = 2.0 mH, R_G = 1 Ω , I_{AR} = 18 A



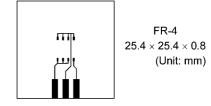


Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)

Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.



6. Electrical Characteristics (T_a = 25°C unless otherwise specified)

6.1. Static Characteristics

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|----------------------|---|-----|------|------|------|
| Gate leakage current | I _{GSS} | $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$ | _ | _ | ±0.1 | μА |
| Drain cut-off current | I _{DSS} | V _{DS} = 30 V, V _{GS} = 0 V | _ | _ | 10 | |
| Drain-source breakdown voltage | V _{(BR)DSS} | I _D = 10 mA, V _{GS} = 0 V | 30 | | | V |
| | V _{(BR)DSX} | I _D = 10 mA, V _{GS} = -20 V | 15 | | | |
| Gate threshold voltage | V_{th} | V _{DS} = 10 V, I _D = 1.0 mA | 1.3 | _ | 2.3 | |
| Drain-source on-resistance | R _{DS(ON)} | V _{GS} = 4.5 V, I _D = 9 A | | 2.4 | 2.9 | mΩ |
| | | V _{GS} = 10 V, I _D = 9 A | _ | 1.9 | 2.4 | |

6.2. Dynamic Characteristics

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|------------------|--|-----|------|-----|------|
| Input capacitance | C _{iss} | V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz | _ | 5200 | _ | pF |
| Reverse transfer capacitance | C _{rss} | | _ | 290 | _ | |
| Output capacitance | C _{oss} | | _ | 1000 | _ | |
| Switching time (rise time) | t _r | See Figure 6.2.1. | _ | 4.1 | _ | ns |
| Switching time (turn-on time) | t _{on} | | _ | 14 | _ | |
| Switching time (fall time) | t _f | | _ | 8.4 | _ | |
| Switching time (turn-off time) | t _{off} | | _ | 64 | _ | |

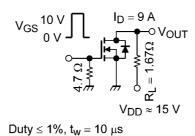


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--|------------------|--|-----|------|-----|------|
| Total gate charge (gate-source plus gate-drain) | Qg | $V_{DD} \approx 24 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 18 \text{ A}$ | | 74 | | nC |
| Gate-source charge 1 | Q _{gs1} | | _ | 16 | | |
| Gate-drain charge | Q_{gd} | | _ | 9.3 | | |

6.4. Source-Drain Characteristics

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---------------------------------------|------------------|---|-----|------|------|------|
| Pulsed reverse drain current (Note 5) | I _{DRP} | _ | _ | _ | 72 | Α |
| Diode forward voltage | V _{DSF} | I _{DR} = 18 A, V _{GS} = 0 V | _ | _ | -1.2 | V |

Note 5: Ensure that the channel temperature does not exceed 150°C.



7. Marking(Note)

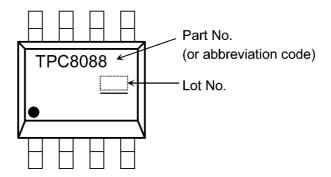


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

8. Characteristics Curves (Note)

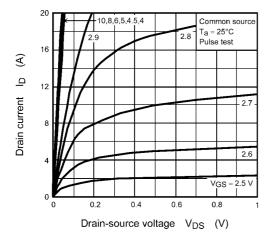


Fig. 8.1 I_D - V_{DS}

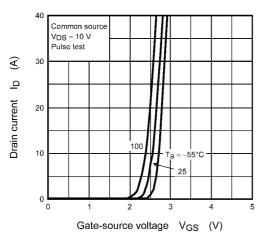


Fig. 8.3 $I_D - V_{GS}$

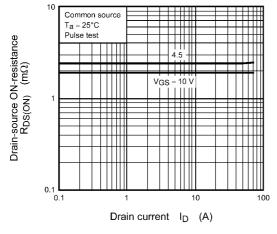


Fig. 8.5 R_{DS(ON)} - I_D

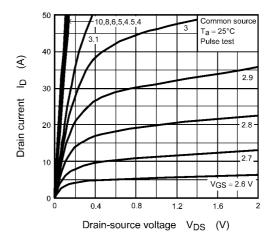


Fig. 8.2 I_D - V_{DS}

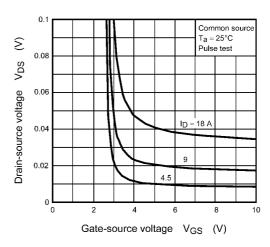


Fig. 8.4 V_{DS} - V_{GS}

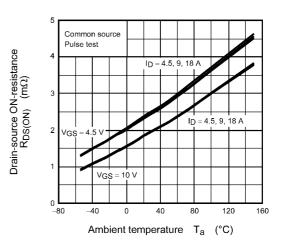


Fig. 8.6 R_{DS(ON)} - T_a

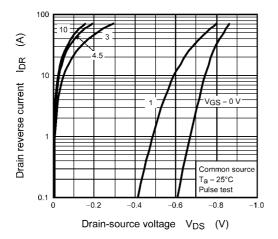


Fig. 8.7 IDR - VDS

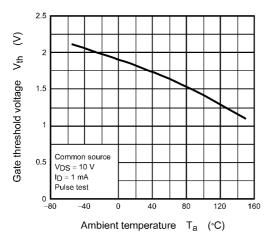


Fig. 8.9 V_{th} - T_a

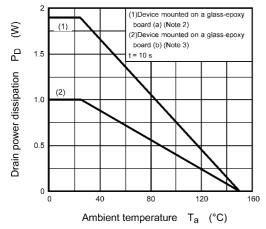


Fig. 8.11 P_D - T_a (Guaranteed Maximum)

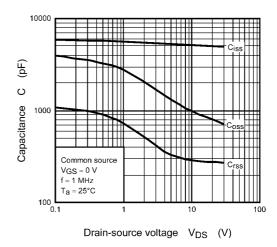


Fig. 8.8 Capacitance - V_{DS}

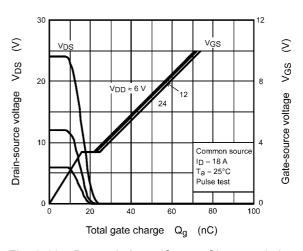


Fig. 8.10 Dynamic Input/Output Characteristics

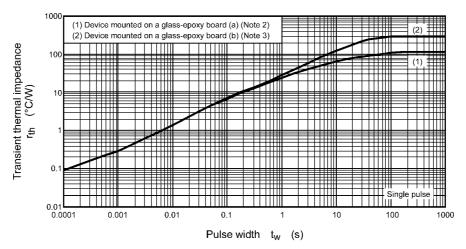


Fig. 8.12 r_{th} - t_w (Guaranteed Maximum)

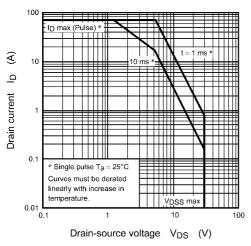


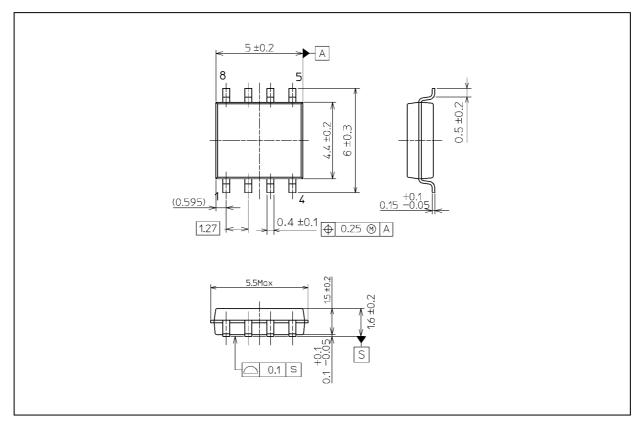
Fig. 8.13 Safe Operating Area (Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 0.085 g (typ.)

| Package Name(s) |
|-----------------|
| TOSHIBA: 2-6J1S |
| Nickname: SOP-8 |



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